CMOS Digital Integrated Circuits Silicon Monolithic

# 74VHCT574AFT

#### 1. Functional Description

Octal D-Type Flip Flop with 3-State Outputs

#### 2. General

The 74VHCT574AFT is an advanced high speed CMOS OCTAL FLIP-FLOP with 3-STATE OUTPUT fabricated with silicon gate C<sup>2</sup>MOS technology.

It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

This 8-bit D-type flip-flop is controlled by a clock input (CK) and an output enable input ( $\overline{\text{OE}}$ ).

When the  $\overline{\text{OE}}$  input is high, the eight outputs are in a high impedance state.

The input voltage is compatible with TTL output voltage.

This device may be used as a level converter for interfacing 3.3 V to 5 V system.

Input protection and output circuit ensure that 0 to 5.5 V can be applied to the input and output (Note) pins without regard to the supply voltage. These structure prevents device destruction due to mismatched supply and input/output voltages such as battery back up, hot board insertion, etc.

Note: Output in off-state

#### 3. Features

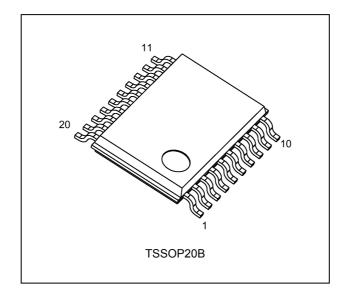
- (1) AEC-Q100 (Rev. H) (Note 1)
- (2) Wide operating temperature range:  $T_{opr} = -40$  to 125 °C
- (3) High speed:  $f_{MAX} = 140 MHz$  (typ.) at  $V_{CC} = 5.0 V$
- (4) Low power dissipation:  $I_{CC}$  = 4.0  $\mu$ A (max) at  $T_a$  = 25°C
- (5) Compatible with TTL inputs:  $V_{IL} = 0.8V$  (max)

#### $V_{IH} = 2.0V \text{ (min)}$

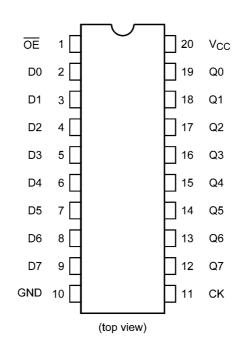
- (6) Power-down protection is provided on all inputs and outputs.
- (7) Balanced propagation delays:  $t_{PLH} \approx t_{PHL}$
- (8) Low noise:  $V_{OLP} = 1.5 V (max)$
- (9) Pin and function compatible with the 74 series (74ACT/HCT/AHCT etc.) 574 type.
- Note 1: This device is compliant with the reliability requirements of AEC-Q100. For details, contact your Toshiba sales representative.

# TOSHIBA

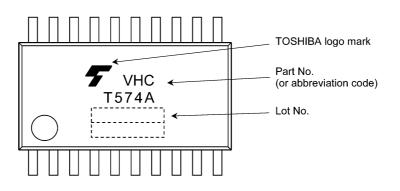
#### 4. Packaging



5. Pin Assignment



#### 6. Marking



## TOSHIBA

#### 7. IEC Logic Symbol

$ \begin{array}{c} \overline{OE} & (1) \\ \overline{CK} & (11) \\ \hline D0 & (2) \\ D1 & (3) \\ \hline D2 & (4) \end{array} $	EN > C1 ] 1D ▷ 5	7 <u>(19)</u> Q0 (18) Q1 (17) 00
D2 (4) D3 (5) D4 (6) D5 (7) D6 (8) D7 (9)		(17) Q2 (16) Q3 (15) Q4 (14) Q5 (13) Q6 (12) Q7

#### 8. Truth Table

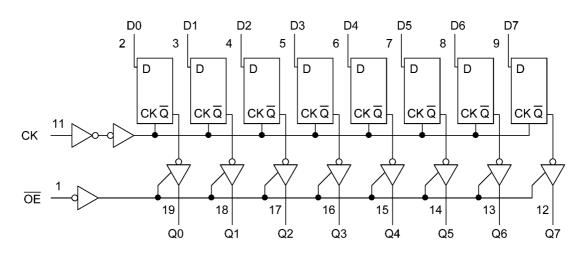
	Inputs		Output			
ŌĒ	ск	D	Output			
Н	Х	Х	Z			
L		Х	Qn			
L		L	L			
L		Н	Н			

X: Don't care

Z: High impedance

Qn: No change

#### 9. System Diagram



#### 10. Absolute Maximum Ratings (Note)

Characteristics	Symbol	Note	Rating	Unit
Supply voltage	V <sub>CC</sub>		-0.5 to 7.0	V
Input voltage	V <sub>IN</sub>		-0.5 to 7.0	V
Output voltage	V <sub>OUT</sub>	(Note 1)	-0.5 to 7.0	V
		(Note 2)	-0.5 to V <sub>CC</sub> + 0.5	
Input diode current	I <sub>IK</sub>		-20	mA
Output diode current	I <sub>OK</sub>	(Note 3)	±20	mA
Output current	I <sub>OUT</sub>		±25	mA
V <sub>CC</sub> /ground current	I <sub>CC</sub>		±75	mA
Power dissipation	PD	(Note 4)	180	mW
Storage temperature	T <sub>stg</sub>		-65 to 150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Output in off-state.

Note 2: High (H) or Low (L) state.  $I_{OUT}$  absolute maximum rating must be observed.

Note 3:  $V_{OUT}$  < GND,  $V_{OUT}$  >  $V_{CC}$ 

Note 4: 180 mW in the range of  $T_a = -40$  to 85 °C. From  $T_a = 85$  to 125 °C a derating factor of -3.25 mW/°C shall be applied until 50 mW.

#### 11. Operating Ranges (Note)

Characteristics	Symbol	Note	Rating	Unit
Supply voltage	V <sub>CC</sub>		4.5 to 5.5	V
Input voltage	V <sub>IN</sub>		0 to 5.5	V
Output voltage	V <sub>OUT</sub>	(Note 1)	0 to 5.5	V
		(Note 2)	0 to V <sub>CC</sub>	
Operating temperature	T <sub>opr</sub>		-40 to 125	°C
Input rise and fall times	dt/dv		0 to 20	ns/V

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either  $V_{CC}$  or GND.

Note 1: Output in Off-state.

Note 2: High (H) or Low (L) state.

#### 12. Electrical Characteristics

#### 12.1. DC Characteristics (Unless otherwise specified, $T_a = 25$ °C)

Characteristics	Symbol	Test Condition	n	V <sub>CC</sub> (V)	Min	Тур.	Max	Unit
High-level input voltage	V <sub>IH</sub>	—		4.5 to 5.5	2.0		_	V
Low-level input voltage	VIL	—		4.5 to 5.5	—		0.8	V
High-level output voltage	V <sub>OH</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OH</sub> = -50 μA	4.5	4.40	4.50	_	V
			I <sub>OH</sub> = -8 mA	4.5	3.94		_	
Low-level output voltage	V <sub>OL</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OL</sub> = 50 μA	4.5	_	0.0	0.10	V
			I <sub>OL</sub> = 8 mA	4.5	_		0.36	
3-state output OFF-state leakage current	I <sub>OZ</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub> V <sub>OUT</sub> = V <sub>CC</sub> or GND		5.5	—	—	±0.25	μA
Input leakage current	I <sub>IN</sub>	V <sub>IN</sub> = 5.5 V or GND		0 to 5.5			±0.1	μA
Quiescent supply current	I <sub>CC</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND		5.5			4.0	μA
	I <sub>CCT</sub>	Per input: V <sub>IN</sub> = 3.4 V Other input: V <sub>CC</sub> or GND		5.5	—	—	1.35	mA
Output leakage current (Power-OFF)	I <sub>OPD</sub>	V <sub>OUT</sub> = 5.5 V		0	—	—	0.5	μA

#### 12.2. DC Characteristics (Unless otherwise specified, $T_a = -40$ to 85 °C)

Characteristics	Symbol	Test Condition	ı	V <sub>CC</sub> (V)	Min	Max	Unit
High-level input voltage	V <sub>IH</sub>	—		4.5 to 5.5	2.0	—	V
Low-level input voltage	V <sub>IL</sub>	—		4.5 to 5.5		0.8	V
High-level output voltage	V <sub>OH</sub>	$V_{IN} = V_{IH}$ or $V_{IL}$	I <sub>OH</sub> = -50 μA	4.5	4.40	—	V
			I <sub>OH</sub> = -8 mA	4.5	3.80	—	
Low-level output voltage	V <sub>OL</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OL</sub> = 50 μA	4.5	_	0.10	V
			I <sub>OL</sub> = 8 mA	4.5	_	0.44	
3-state output OFF-state leakage current	I <sub>OZ</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub> V <sub>OUT</sub> = V <sub>CC</sub> or GND		5.5	_	±2.50	μA
Input leakage current	I <sub>IN</sub>	V <sub>IN</sub> = 5.5 V or GND		0 to 5.5	_	±1.0	μA
Quiescent supply current	I <sub>CC</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND		5.5	_	40.0	μA
	I <sub>CCT</sub>	Per input: V <sub>IN</sub> = 3.4 V Other input: V <sub>CC</sub> or GND		5.5	_	1.50	mA
Output leakage current (Power-OFF)	I <sub>OPD</sub>	V <sub>OUT</sub> = 5.5 V		0	_	5.0	μΑ

### 12.3. DC Characteristics (Unless otherwise specified, $T_a = -40$ to 125 °C)

Characteristics	Symbol	Test Condition	n	V <sub>CC</sub> (V)	Min	Max	Unit
High-level input voltage	V <sub>IH</sub>	—		4.5 to 5.5	2.0	_	V
Low-level input voltage	VIL	_		4.5 to 5.5	_	0.8	V
High-level output voltage	V <sub>OH</sub>	$V_{IN} = V_{IH}$ or $V_{IL}$	I <sub>OH</sub> = -50 μA	4.5	4.40	—	V
			I <sub>OH</sub> = -8 mA	4.5	3.70	_	
Low-level output voltage	V <sub>OL</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OL</sub> = 50 μA	4.5	_	0.10	V
			I <sub>OL</sub> = 8 mA	4.5	_	0.55	
3-state output OFF-state leakage current	I <sub>OZ</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub> V <sub>OUT</sub> = V <sub>CC</sub> or GND		5.5	—	±10.0	μA
Input leakage current	I <sub>IN</sub>	V <sub>IN</sub> = 5.5 V or GND		0 to 5.5	_	±2.0	μA
Quiescent supply current	I <sub>CC</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND		5.5	_	80.0	μA
	I <sub>CCT</sub>	Per input: V <sub>IN</sub> = 3.4 V Other input: V <sub>CC</sub> or GND		5.5	—	1.50	mA
Output leakage current (Power-OFF)	I <sub>OPD</sub>	V <sub>OUT</sub> = 5.5 V		0	—	20.0	μA

#### 12.4. Timing Requirements (Unless otherwise specified, $T_a = 25^{\circ}C$ , Input: $t_r = t_f = 3 \text{ ns}$ )

Characteristics	Symbol	V <sub>CC</sub> (V)	Тур.	Limit	Unit
Minimum pulse width (CK)	$t_{w(L)}, t_{w(H)}$	$5.0\pm0.5$	_	6.5	ns
Minimum setup time	t <sub>S</sub>	$5.0\pm0.5$	_	2.5	ns
Minimum hold time	t <sub>h</sub>	$5.0\pm0.5$	_	2.5	ns

#### 12.5. Timing Requirements

(Unless otherwise specified,  $T_a = -40$  to 85°C, Input:  $t_r = t_f = 3$  ns)

Characteristics	Symbol	V <sub>CC</sub> (V)	Limit	Unit
Minimum pulse width (CK)	$t_{w(L)}, t_{w(H)}$	$5.0\pm0.5$	8.5	ns
Minimum setup time	t <sub>S</sub>	$5.0\pm0.5$	2.5	ns
Minimum hold time	t <sub>h</sub>	$5.0\pm0.5$	2.5	ns

#### 12.6. Timing Requirements (Unless otherwise specified, $T_a = -40$ to 125 °C, Input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	V <sub>CC</sub> (V)	Limit	Unit
Minimum pulse width (CK)	$t_{w(L)}, t_{w(H)}$	$5.0\pm0.5$	8.5	ns
Minimum setup time	t <sub>S</sub>	$5.0\pm0.5$	3.0	ns
Minimum hold time	t <sub>h</sub>	$5.0\pm0.5$	2.5	ns

#### 12.7. AC Characteristics (Unless otherwise specified, $T_a = 25$ °C, Input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	Note	Test Condition	V <sub>CC</sub> (V)	C <sub>L</sub> (pF)	Min	Тур.	Max	Unit
Propagation delay time	t <sub>PLH</sub> ,t <sub>PHL</sub>		—	$5.0\pm0.5$	15	_	4.1	9.4	ns
(CK-Q)					50		5.6	10.4	
3-state output enable time	t <sub>PZL</sub> ,t <sub>PZH</sub>		R <sub>L</sub> = 1 kΩ	$5.0\pm0.5$	15		6.5	10.2	ns
					50	_	7.3	11.2	
3-state output disable time	t <sub>PLZ</sub> ,t <sub>PHZ</sub>		R <sub>L</sub> = 1 kΩ	$5.0\pm0.5$	50		7.0	11.2	ns
Maximum clock frequency	f <sub>MAX</sub>		_	$5.0\pm0.5$	15	90	140	_	MHz
					50	85	130	_	
Output skew	t <sub>osLH</sub> ,t <sub>osHL</sub>	(Note 1)	—	$5.0\pm0.5$	50	_		1.0	ns
Input capacitance	C <sub>IN</sub>		_				4	10	pF
Output capacitance	C <sub>OUT</sub>		—			_	9		pF
Power dissipation capacitance	C <sub>PD</sub>	(Note 2)					25	_	pF

Note 1: Parameter guaranteed by design. ( $t_{osLH} = |t_{PLH}m-t_{PLH}n|$ ,  $t_{osHL} = |t_{PHL}m-t_{PHL}n|$ )

Note 2: C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation.

 $I_{CC(opr)} = C_{PD} \times V_{CC} \times f_{IN} + I_{CC}/8 \text{ (per F/F)}$ 

And the total  $C_{PD}$  when n pcs of F/F operate can be gained by the following equation.

 $C_{PD}$  (total) = 14 + 11 × n

#### 12.8. AC Characteristics

#### (Unless otherwise specified, $T_a = -40$ to 85 °C, Input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	Note	Test Condition	V <sub>CC</sub> (V)	C <sub>L</sub> (pF)	Min	Max	Unit
Propagation delay time	t <sub>PLH</sub> ,t <sub>PHL</sub>		—	$5.0\pm0.5$	15	1.0	10.5	ns
(CK-Q)					50	1.0	11.5	
3-state output enable time	t <sub>PZL</sub> ,t <sub>PZH</sub>		R <sub>L</sub> = 1 kΩ	$5.0\pm0.5$	15	1.0	11.5	ns
					50	1.0	12.5	
3-state output disable time	t <sub>PLZ</sub> ,t <sub>PHZ</sub>		R <sub>L</sub> = 1 kΩ	$5.0\pm0.5$	50	1.0	12.0	ns
Maximum clock frequency	f <sub>MAX</sub>		—	$5.0\pm0.5$	15	80	_	MHz
					50	75	—	
Output skew	t <sub>osLH</sub> ,t <sub>osHL</sub>	(Note 1)	—	$5.0\pm0.5$	50	_	1.0	ns
Input capacitance	C <sub>IN</sub>		_			_	10	pF

Note 1: Parameter guaranteed by design. ( $t_{osLH} = |t_{PLH}m-t_{PLH}n|$ ,  $t_{osHL} = |t_{PHL}m-t_{PHL}n|$ )

#### 12.9. AC Characteristics

#### (Unless otherwise specified, $T_a = -40$ to 125 °C, Input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	Note	Test Condition	V <sub>CC</sub> (V)	$C_L (pF)$	Min	Max	Unit
Propagation delay time	t <sub>PLH</sub> ,t <sub>PHL</sub>		—	$5.0\pm0.5$	15	1.0	12.0	ns
(CK-Q)					50	1.0	13.0	]
3-state output enable time	t <sub>PZL</sub> ,t <sub>PZH</sub>		R <sub>L</sub> = 1 kΩ	$5.0\pm0.5$	15	1.0	13.0	ns
					50	1.0	14.0	1
3-state output disable time	t <sub>PLZ</sub> ,t <sub>PHZ</sub>		R <sub>L</sub> = 1 kΩ	$5.0\pm0.5$	50	1.0	14.0	ns
Maximum clock frequency	f <sub>MAX</sub>		_	$5.0\pm0.5$	15	70	_	MHz
				$5.0\pm0.5$	50	65	_	1
Output skew	t <sub>osLH</sub> ,t <sub>osHL</sub>	(Note 1)	_	$5.0\pm0.5$	50	_	1.0	ns
Input capacitance	C <sub>IN</sub>		_			_	10	pF

Note 1: Parameter guaranteed by design. ( $t_{osLH} = |t_{PLH}m-t_{PLH}n|$ ,  $t_{osHL} = |t_{PHL}m-t_{PHL}n|$ )

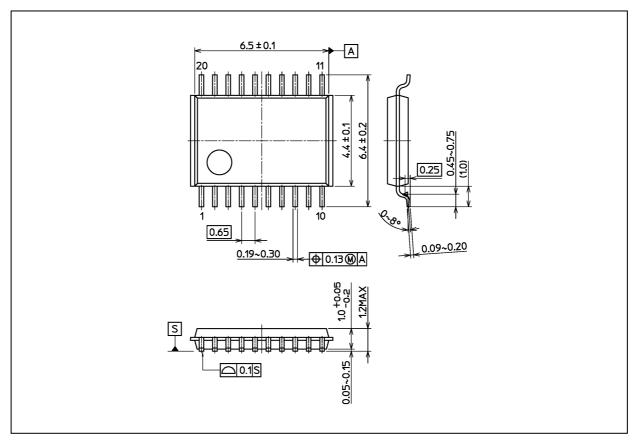
#### 12.10. Noise Characteristics (Unless otherwise specified, $T_a = 25^{\circ}C$ , Input: $t_r = t_f = 3 \text{ ns}$ )

Characteristics	Symbol	Test Condition	V <sub>CC</sub> (V)	Тур.	Limit	Unit
Quiet output maximum dynamic V <sub>OL</sub>	V <sub>OLP</sub>	C <sub>L</sub> = 50 pF	5.0	1.1	1.5	V
Quiet output minimum dynamic V <sub>OL</sub>	V <sub>OLV</sub>	C <sub>L</sub> = 50 pF	5.0	-1.1	-1.5	V
Minimum high-level dynamic input voltage	V <sub>IHD</sub>	C <sub>L</sub> = 50 pF	5.0	_	2.0	V
Maximum low-level dynamic input voltage	V <sub>ILD</sub>	C <sub>L</sub> = 50 pF	5.0		0.8	V



#### **Package Dimensions**

Unit: mm



Weight: 0.071 g (typ.)

	Package Name(s)		
Nickname: TSSOP20B			

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